



DOCKET NO. PHUS010610

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Letavic et al. ) Examiner: Lewis, M.  
Application No.: 10/015,847 )  
Filed: 12/10/2001 )  
For: DUAL GATE OXIDE HIGH-VOLTAGE )  
SEMICONDUCTOR DEVICE )  
(as Amended) )

8/B Amend  
w/ Way  
3-11-03  
A. Waller

Commissioner for Patents  
Washington D.C. 20231

AMENDMENT

Sir:

In response to the Office Action of December 19, 2002, please amend the application as follows:

In the Drawings

Please amend FIG. 1 and FIG. 2 as indicated in red in the attached Submission of Proposed Drawing Amendment for Approval of Examiner.

RECEIVED  
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